

# MUN2113, MMUN2113L, MUN5113, DTA144EE, DTA144EM3, NSBA144EF3

## Digital Transistors (BRT) R1 = 47 k $\Omega$ , R2 = 47 k $\Omega$

### PNP Transistors with Monolithic Bias Resistor Network

This series of digital transistors is designed to replace a single device and its external resistor bias network. The Bias Resistor Transistor (BRT) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space.

#### Features

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

#### MAXIMUM RATINGS (T<sub>A</sub> = 25°C)

| Rating                         | Symbol               | Max | Unit |
|--------------------------------|----------------------|-----|------|
| Collector-Base Voltage         | V <sub>CBO</sub>     | 50  | Vdc  |
| Collector-Emitter Voltage      | V <sub>CEO</sub>     | 50  | Vdc  |
| Collector Current – Continuous | I <sub>C</sub>       | 100 | mAdc |
| Input Forward Voltage          | V <sub>IN(fwd)</sub> | 40  | Vdc  |
| Input Reverse Voltage          | V <sub>IN(rev)</sub> | 10  | Vdc  |

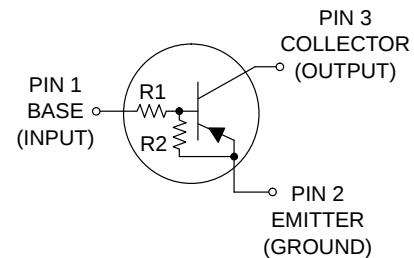
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



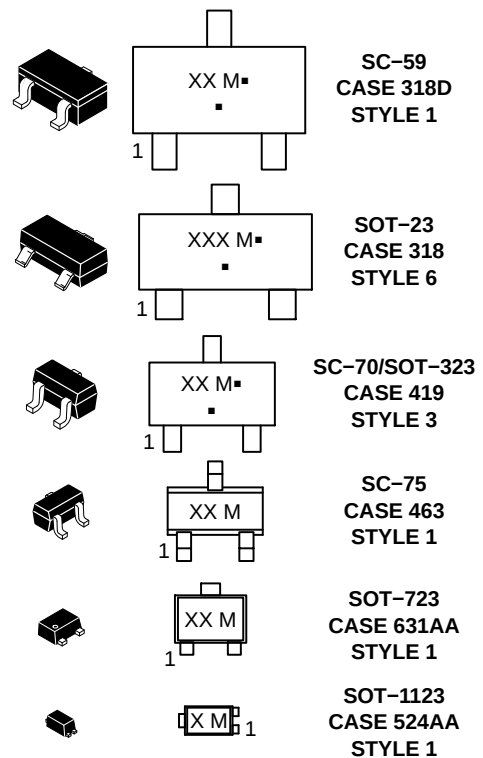
ON Semiconductor®

[www.onsemi.com](http://www.onsemi.com)

#### PIN CONNECTIONS



#### MARKING DIAGRAMS



XXX = Specific Device Code  
M = Date Code\*  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation may vary depending upon manufacturing location.

#### ORDERING INFORMATION

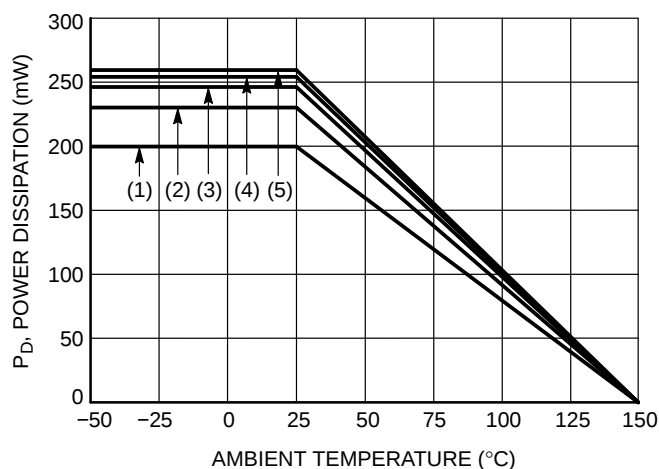
See detailed ordering, marking, and shipping information in the package dimensions section on page 2 of this data sheet.

Table 1. ORDERING INFORMATION

| Device                         | Part Marking | Package                    | Shipping <sup>†</sup> |
|--------------------------------|--------------|----------------------------|-----------------------|
| MUN2113T1G, SMUN2113T1G*       | 6C           | SC-59<br>(Pb-Free)         | 3000 / Tape & Reel    |
| MMUN2113LT1G, SMMUN2113LT1G*   | A6C          | SOT-23<br>(Pb-Free)        | 3000 / Tape & Reel    |
| MMUN2113LT3G, NSVMMUN2113LT3G* | A6C          | SOT-23<br>(Pb-Free)        | 10000 / Tape & Reel   |
| MUN5113T1G, SMUN5113T1G*       | 6C           | SC-70/SOT-323<br>(Pb-Free) | 3000 / Tape & Reel    |
| MUN5113T3G                     | 6C           | SC-70/SOT-323<br>(Pb-Free) | 10000 / Tape & Reel   |
| DTA144EET1G, NSVDTA144EET1G*   | 6C           | SC-75<br>(Pb-Free)         | 3000 / Tape & Reel    |
| DTA144EM3T5G                   | 6C           | SOT-723<br>(Pb-Free)       | 8000 / Tape & Reel    |
| NSBA144EF3T5G                  | E            | SOT-1123<br>(Pb-Free)      | 8000 / Tape & Reel    |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.



- (1) SC-75 and SC-70/SOT-323; Minimum Pad
- (2) SC-59; Minimum Pad
- (3) SOT-23; Minimum Pad
- (4) SOT-1123; 100 mm², 1 oz. copper trace
- (5) SOT-723; Minimum Pad

Figure 1. Derating Curve

Table 2. THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|----------------|--------|-----|------|
|----------------|--------|-----|------|

**THERMAL CHARACTERISTICS (SC-59) (MUN2113)**

|                                                                                                                                   |                 |                          |                                |
|-----------------------------------------------------------------------------------------------------------------------------------|-----------------|--------------------------|--------------------------------|
| Total Device Dissipation<br>$T_A = 25^\circ\text{C}$ (Note 1)<br>(Note 2)<br>Derate above $25^\circ\text{C}$ (Note 1)<br>(Note 2) | $P_D$           | 230<br>338<br>1.8<br>2.7 | mW<br><br>mW/ $^\circ\text{C}$ |
| Thermal Resistance,<br>Junction to Ambient (Note 1)<br>(Note 2)                                                                   | $R_{\theta JA}$ | 540<br>370               | $^\circ\text{C/W}$             |
| Thermal Resistance,<br>Junction to Lead (Note 1)<br>(Note 2)                                                                      | $R_{\theta JL}$ | 264<br>287               | $^\circ\text{C/W}$             |
| Junction and Storage Temperature Range                                                                                            | $T_J, T_{stg}$  | -55 to +150              | $^\circ\text{C}$               |

**THERMAL CHARACTERISTICS (SOT-23) (MMUN2113L)**

|                                                                                                                                   |                 |                          |                                |
|-----------------------------------------------------------------------------------------------------------------------------------|-----------------|--------------------------|--------------------------------|
| Total Device Dissipation<br>$T_A = 25^\circ\text{C}$ (Note 1)<br>(Note 2)<br>Derate above $25^\circ\text{C}$ (Note 1)<br>(Note 2) | $P_D$           | 246<br>400<br>2.0<br>3.2 | mW<br><br>mW/ $^\circ\text{C}$ |
| Thermal Resistance,<br>Junction to Ambient (Note 1)<br>(Note 2)                                                                   | $R_{\theta JA}$ | 508<br>311               | $^\circ\text{C/W}$             |
| Thermal Resistance,<br>Junction to Lead (Note 1)<br>(Note 2)                                                                      | $R_{\theta JL}$ | 174<br>208               | $^\circ\text{C/W}$             |
| Junction and Storage Temperature Range                                                                                            | $T_J, T_{stg}$  | -55 to +150              | $^\circ\text{C}$               |

**THERMAL CHARACTERISTICS (SC-70/SOT-323) (MUN5113)**

|                                                                                                                                   |                 |                          |                                |
|-----------------------------------------------------------------------------------------------------------------------------------|-----------------|--------------------------|--------------------------------|
| Total Device Dissipation<br>$T_A = 25^\circ\text{C}$ (Note 1)<br>(Note 2)<br>Derate above $25^\circ\text{C}$ (Note 1)<br>(Note 2) | $P_D$           | 202<br>310<br>1.6<br>2.5 | mW<br><br>mW/ $^\circ\text{C}$ |
| Thermal Resistance,<br>Junction to Ambient (Note 1)<br>(Note 2)                                                                   | $R_{\theta JA}$ | 618<br>403               | $^\circ\text{C/W}$             |
| Thermal Resistance,<br>Junction to Lead (Note 1)<br>(Note 2)                                                                      | $R_{\theta JL}$ | 280<br>332               | $^\circ\text{C/W}$             |
| Junction and Storage Temperature Range                                                                                            | $T_J, T_{stg}$  | -55 to +150              | $^\circ\text{C}$               |

**THERMAL CHARACTERISTICS (SC-75) (DTA144EE)**

|                                                                                                                                   |                 |                          |                                |
|-----------------------------------------------------------------------------------------------------------------------------------|-----------------|--------------------------|--------------------------------|
| Total Device Dissipation<br>$T_A = 25^\circ\text{C}$ (Note 1)<br>(Note 2)<br>Derate above $25^\circ\text{C}$ (Note 1)<br>(Note 2) | $P_D$           | 200<br>300<br>1.6<br>2.4 | mW<br><br>mW/ $^\circ\text{C}$ |
| Thermal Resistance,<br>Junction to Ambient (Note 1)<br>(Note 2)                                                                   | $R_{\theta JA}$ | 600<br>400               | $^\circ\text{C/W}$             |
| Junction and Storage Temperature Range                                                                                            | $T_J, T_{stg}$  | -55 to +150              | $^\circ\text{C}$               |

**THERMAL CHARACTERISTICS (SOT-723) (DTA144EM3)**

|                                                                                                                                   |                 |                          |                                |
|-----------------------------------------------------------------------------------------------------------------------------------|-----------------|--------------------------|--------------------------------|
| Total Device Dissipation<br>$T_A = 25^\circ\text{C}$ (Note 1)<br>(Note 2)<br>Derate above $25^\circ\text{C}$ (Note 1)<br>(Note 2) | $P_D$           | 260<br>600<br>2.0<br>4.8 | mW<br><br>mW/ $^\circ\text{C}$ |
| Thermal Resistance,<br>Junction to Ambient (Note 1)<br>(Note 2)                                                                   | $R_{\theta JA}$ | 480<br>205               | $^\circ\text{C/W}$             |
| Junction and Storage Temperature Range                                                                                            | $T_J, T_{stg}$  | -55 to +150              | $^\circ\text{C}$               |

1. FR-4 @ Minimum Pad.
2. FR-4 @ 1.0 x 1.0 Inch Pad.
3. FR-4 @ 100 mm<sup>2</sup>, 1 oz. copper traces, still air.
4. FR-4 @ 500 mm<sup>2</sup>, 1 oz. copper traces, still air.

**Table 2. THERMAL CHARACTERISTICS**

| Characteristic                                                                                                   | Symbol                            | Max                      | Unit        |
|------------------------------------------------------------------------------------------------------------------|-----------------------------------|--------------------------|-------------|
| <b>THERMAL CHARACTERISTICS (SOT-1123) (NSBA144EF3)</b>                                                           |                                   |                          |             |
| Total Device Dissipation<br>T <sub>A</sub> = 25°C (Note 3)<br>(Note 4)<br>Derate above 25°C (Note 3)<br>(Note 4) | P <sub>D</sub>                    | 254<br>297<br>2.0<br>2.4 | mW<br>mW/°C |
| Thermal Resistance, Junction to Ambient<br>(Note 3)<br>(Note 4)                                                  | R <sub>θJA</sub>                  | 493<br>421               | °C/W        |
| Thermal Resistance, Junction to Lead<br>(Note 3)                                                                 | R <sub>θJL</sub>                  | 193                      | °C/W        |
| Junction and Storage Temperature Range                                                                           | T <sub>J</sub> , T <sub>stg</sub> | -55 to +150              | °C          |

1. FR-4 @ Minimum Pad.
2. FR-4 @ 1.0 x 1.0 Inch Pad.
3. FR-4 @ 100 mm<sup>2</sup>, 1 oz. copper traces, still air.
4. FR-4 @ 500 mm<sup>2</sup>, 1 oz. copper traces, still air.

**Table 3. ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C, unless otherwise noted)

| Characteristic                                                                                     | Symbol                         | Min  | Typ | Max  | Unit |
|----------------------------------------------------------------------------------------------------|--------------------------------|------|-----|------|------|
| <b>OFF CHARACTERISTICS</b>                                                                         |                                |      |     |      |      |
| Collector-Base Cutoff Current<br>(V <sub>CB</sub> = 50 V, I <sub>E</sub> = 0)                      | I <sub>CBO</sub>               | –    | –   | 100  | nAdc |
| Collector-Emitter Cutoff Current<br>(V <sub>CE</sub> = 50 V, I <sub>B</sub> = 0)                   | I <sub>CEO</sub>               | –    | –   | 500  | nAdc |
| Emitter-Base Cutoff Current<br>(V <sub>EB</sub> = 6.0 V, I <sub>C</sub> = 0)                       | I <sub>EBO</sub>               | –    | –   | 0.1  | mAdc |
| Collector-Base Breakdown Voltage<br>(I <sub>C</sub> = 10 μA, I <sub>E</sub> = 0)                   | V <sub>(BR)CBO</sub>           | 50   | –   | –    | Vdc  |
| Collector-Emitter Breakdown Voltage (Note 5)<br>(I <sub>C</sub> = 2.0 mA, I <sub>B</sub> = 0)      | V <sub>(BR)CEO</sub>           | 50   | –   | –    | Vdc  |
| <b>ON CHARACTERISTICS</b>                                                                          |                                |      |     |      |      |
| DC Current Gain (Note 5)<br>(I <sub>C</sub> = 5.0 mA, V <sub>CE</sub> = 10 V)                      | h <sub>FE</sub>                | 80   | 140 | –    |      |
| Collector-Emitter Saturation Voltage (Note 5)<br>(I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0.3 mA) | V <sub>CE(sat)</sub>           | –    | –   | 0.25 | Vdc  |
| Input Voltage (off)<br>(V <sub>CE</sub> = 5.0 V, I <sub>C</sub> = 100 μA)                          | V <sub>i(off)</sub>            | –    | 1.2 | 0.8  | Vdc  |
| Input Voltage (on)<br>(V <sub>CE</sub> = 0.3 V, I <sub>C</sub> = 2.0 mA)                           | V <sub>i(on)</sub>             | 3.0  | 1.6 | –    | Vdc  |
| Output Voltage (on)<br>(V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 3.5 V, R <sub>L</sub> = 1.0 kΩ)  | V <sub>OL</sub>                | –    | –   | 0.2  | Vdc  |
| Output Voltage (off)<br>(V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 0.5 V, R <sub>L</sub> = 1.0 kΩ) | V <sub>OH</sub>                | 4.9  | –   | –    | Vdc  |
| Input Resistor                                                                                     | R <sub>1</sub>                 | 32.9 | 47  | 61.1 | kΩ   |
| Resistor Ratio                                                                                     | R <sub>1</sub> /R <sub>2</sub> | 0.8  | 1.0 | 1.2  |      |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

5. Pulsed Condition: Pulse Width = 300 msec, Duty Cycle ≤ 2%.

TYPICAL CHARACTERISTICS  
MUN2113, MMUN2113L, MUN5113, DTA144EE, DTA144EM3

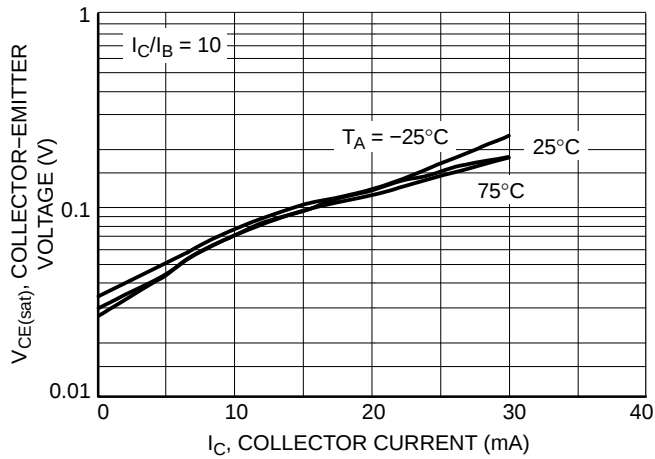


Figure 2.  $V_{CE(sat)}$  vs.  $I_C$

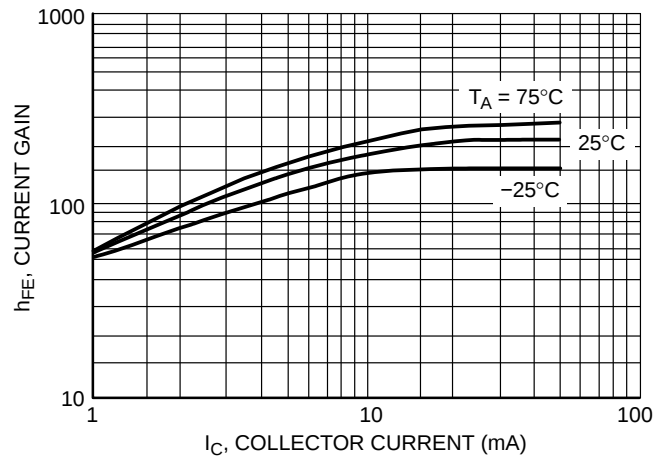


Figure 3. DC Current Gain

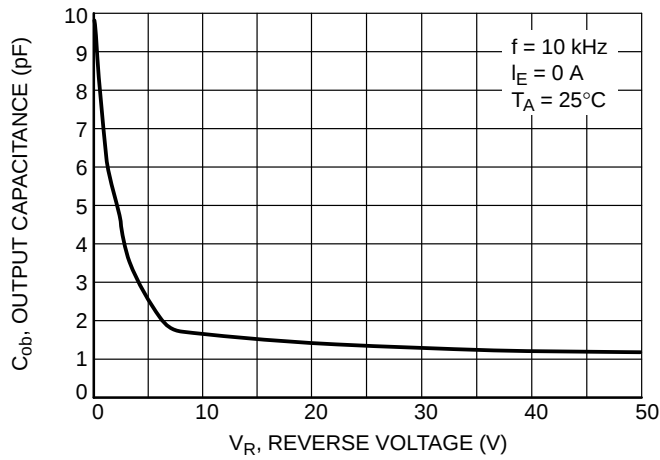


Figure 4. Output Capacitance

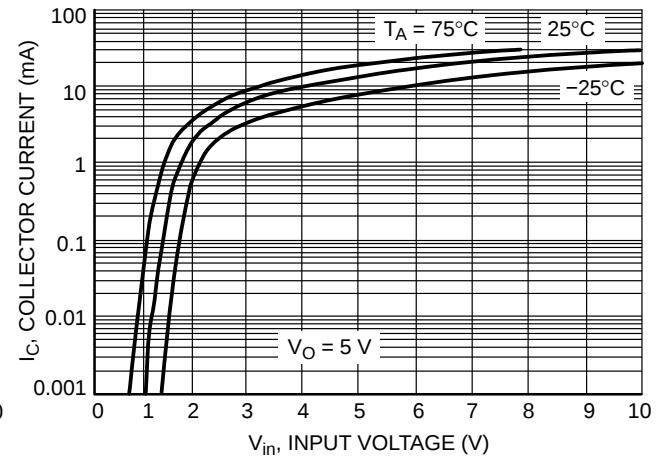


Figure 5. Output Current vs. Input Voltage

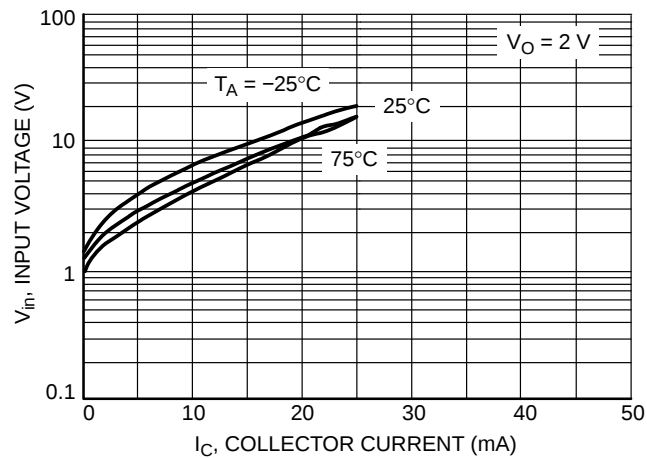


Figure 6. Input Voltage vs. Output Current

TYPICAL CHARACTERISTICS – NSBA144EF3

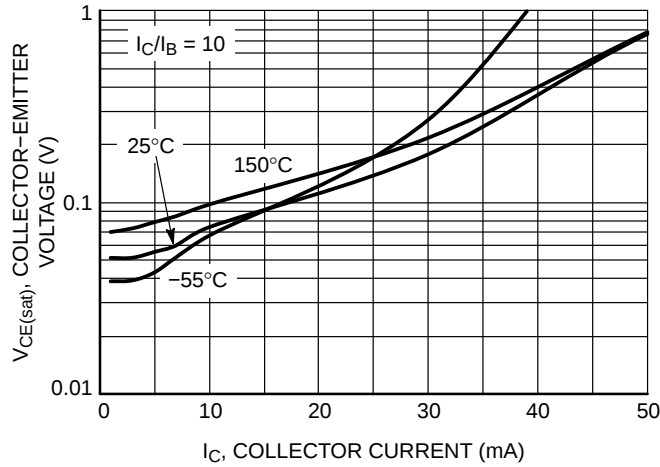


Figure 7.  $V_{CE(sat)}$  vs.  $I_C$

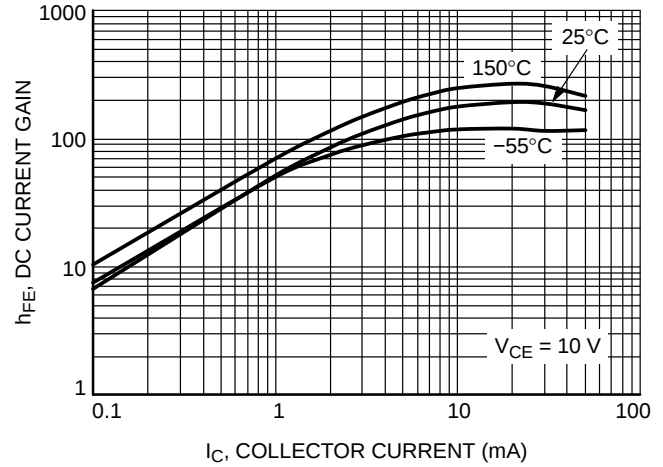


Figure 8. DC Current Gain

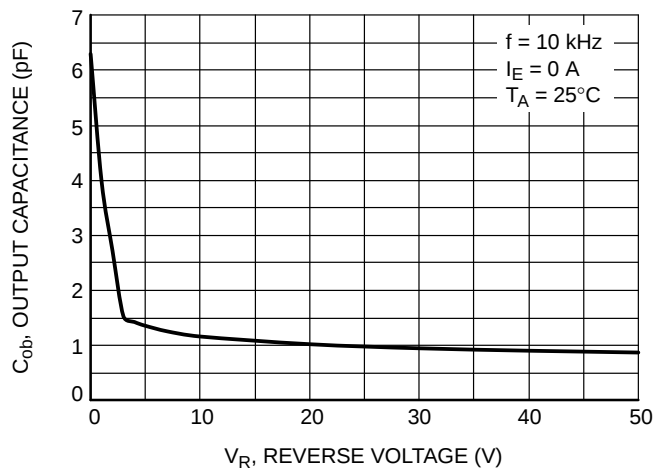


Figure 9. Output Capacitance

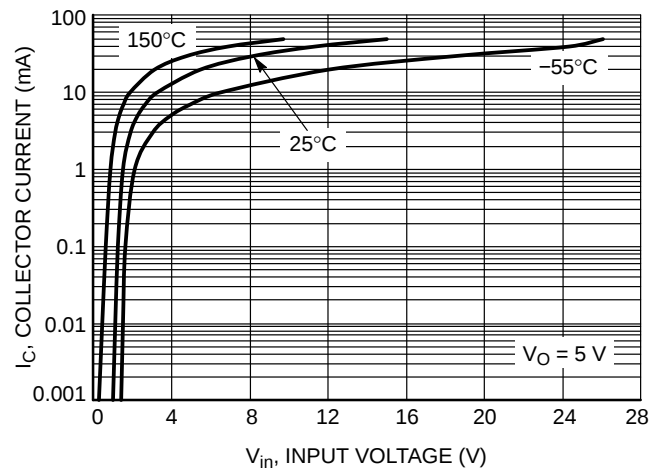


Figure 10. Output Current vs. Input Voltage

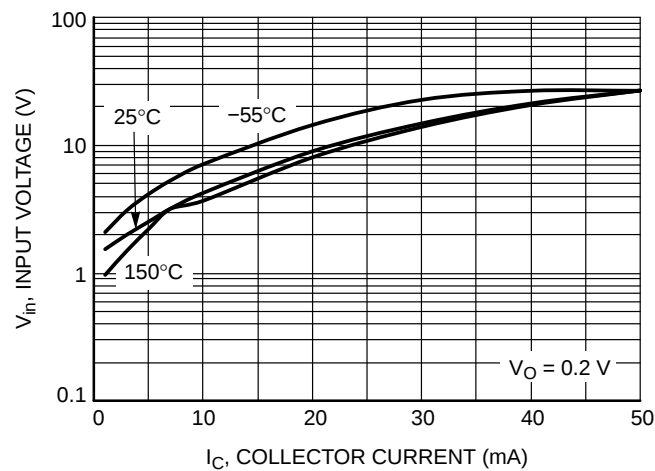
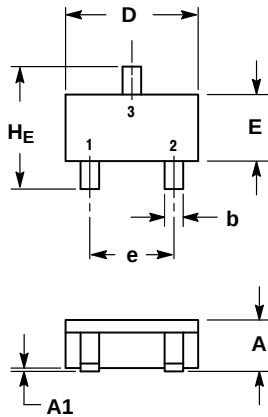


Figure 11. Input Voltage vs. Output Current

PACKAGE DIMENSIONS

SC-59  
CASE 318D-04  
ISSUE H



NOTES:

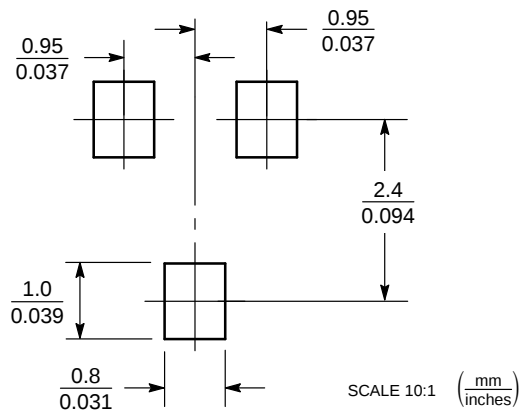
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.

| DIM | MILLIMETERS |      |      | INCHES |       |       |
|-----|-------------|------|------|--------|-------|-------|
|     | MIN         | NOM  | MAX  | MIN    | NOM   | MAX   |
| A   | 1.00        | 1.15 | 1.30 | 0.039  | 0.045 | 0.051 |
| A1  | 0.01        | 0.06 | 0.10 | 0.001  | 0.002 | 0.004 |
| b   | 0.35        | 0.43 | 0.50 | 0.014  | 0.017 | 0.020 |
| c   | 0.09        | 0.14 | 0.18 | 0.003  | 0.005 | 0.007 |
| D   | 2.70        | 2.90 | 3.10 | 0.106  | 0.114 | 0.122 |
| E   | 1.30        | 1.50 | 1.70 | 0.051  | 0.059 | 0.067 |
| e   | 1.70        | 1.90 | 2.10 | 0.067  | 0.075 | 0.083 |
| L   | 0.20        | 0.40 | 0.60 | 0.008  | 0.016 | 0.024 |
| HE  | 2.50        | 2.80 | 3.00 | 0.099  | 0.110 | 0.118 |

STYLE 1:

- PIN 1. BASE
- EMITTER
- COLLECTOR

SOLDERING FOOTPRINT\*



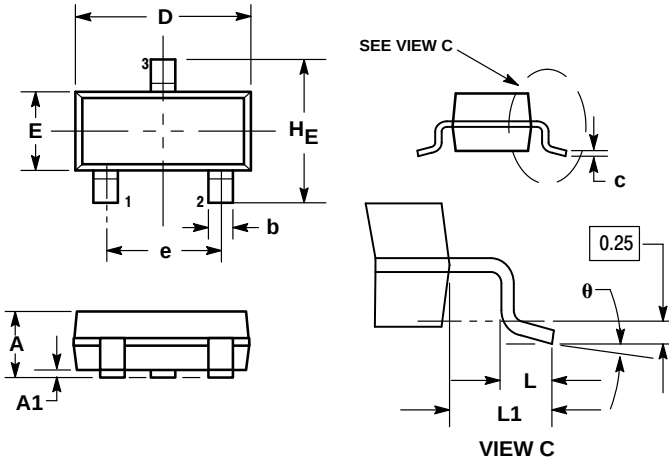
\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## PACKAGE DIMENSIONS

## SOT-23 (TO-236)

CASE 318-08

ISSUE AP



## NOTES:

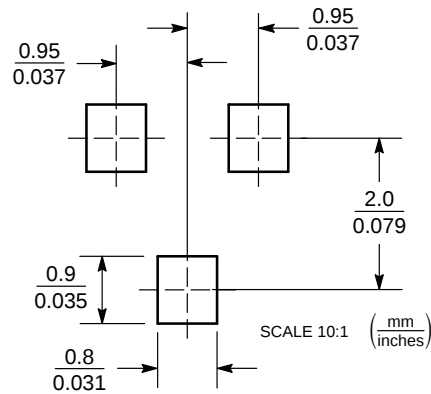
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

| DIM | MILLIMETERS |      |      | INCHES |       |       |
|-----|-------------|------|------|--------|-------|-------|
|     | MIN         | NOM  | MAX  | MIN    | NOM   | MAX   |
| A   | 0.89        | 1.00 | 1.11 | 0.035  | 0.040 | 0.044 |
| A1  | 0.01        | 0.06 | 0.10 | 0.001  | 0.002 | 0.004 |
| b   | 0.37        | 0.44 | 0.50 | 0.015  | 0.018 | 0.020 |
| c   | 0.09        | 0.13 | 0.18 | 0.003  | 0.005 | 0.007 |
| D   | 2.80        | 2.90 | 3.04 | 0.110  | 0.114 | 0.120 |
| E   | 1.20        | 1.30 | 1.40 | 0.047  | 0.051 | 0.055 |
| e   | 1.78        | 1.90 | 2.04 | 0.070  | 0.075 | 0.081 |
| L   | 0.10        | 0.20 | 0.30 | 0.004  | 0.008 | 0.012 |
| L1  | 0.35        | 0.54 | 0.69 | 0.014  | 0.021 | 0.029 |
| HE  | 2.10        | 2.40 | 2.64 | 0.083  | 0.094 | 0.104 |
| θ   | 0°          | ---  | 10°  | 0°     | ---   | 10°   |

## STYLE 6:

- PIN 1. BASE
- EMITTER
- COLLECTOR

## SOLDERING FOOTPRINT

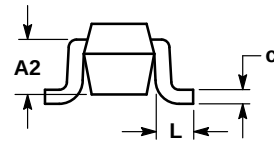
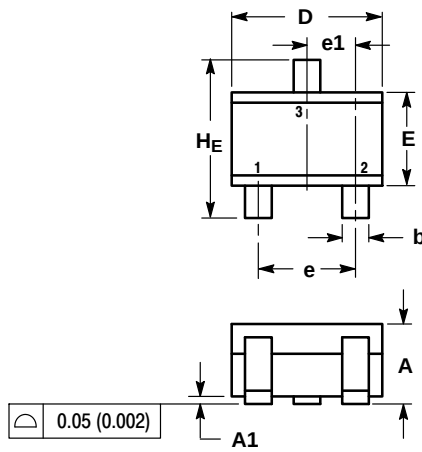


# PACKAGE DIMENSIONS

## SC-70 (SOT-323)

CASE 419-04

ISSUE N



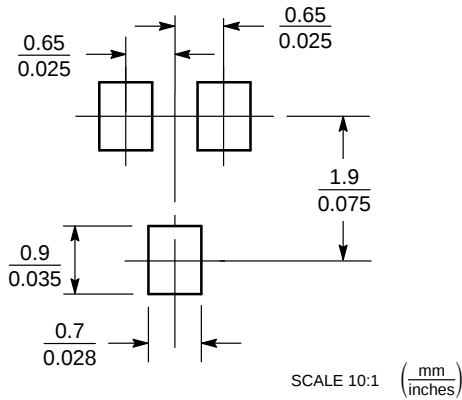
### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

| DIM | MILLIMETERS |      |      | INCHES    |       |       |
|-----|-------------|------|------|-----------|-------|-------|
|     | MIN         | NOM  | MAX  | MIN       | NOM   | MAX   |
| A   | 0.80        | 0.90 | 1.00 | 0.032     | 0.035 | 0.040 |
| A1  | 0.00        | 0.05 | 0.10 | 0.000     | 0.002 | 0.004 |
| A2  | 0.70 REF    |      |      | 0.028 REF |       |       |
| b   | 0.30        | 0.35 | 0.40 | 0.012     | 0.014 | 0.016 |
| c   | 0.10        | 0.18 | 0.25 | 0.004     | 0.007 | 0.010 |
| D   | 1.80        | 2.10 | 2.20 | 0.071     | 0.083 | 0.087 |
| E   | 1.15        | 1.24 | 1.35 | 0.045     | 0.049 | 0.053 |
| e   | 1.20        | 1.30 | 1.40 | 0.047     | 0.051 | 0.055 |
| e1  | 0.65 BSC    |      |      | 0.026 BSC |       |       |
| L   | 0.20        | 0.38 | 0.56 | 0.008     | 0.015 | 0.022 |
| He  | 2.00        | 2.10 | 2.40 | 0.079     | 0.083 | 0.095 |

STYLE 3:  
PIN 1. BASE  
2. EMITTER  
3. COLLECTOR

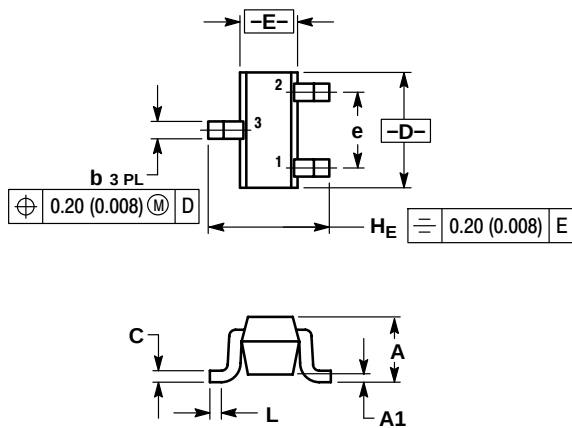
## SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# PACKAGE DIMENSIONS

## SC-75/SOT-416 CASE 463 ISSUE F

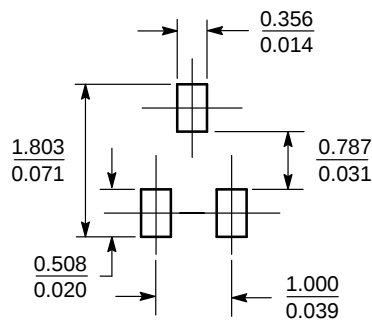


- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.

| DIM            | MILLIMETERS |      |      | INCHES   |       |       |
|----------------|-------------|------|------|----------|-------|-------|
|                | MIN         | NOM  | MAX  | MIN      | NOM   | MAX   |
| A              | 0.70        | 0.80 | 0.90 | 0.027    | 0.031 | 0.035 |
| A1             | 0.00        | 0.05 | 0.10 | 0.000    | 0.002 | 0.004 |
| b              | 0.15        | 0.20 | 0.30 | 0.006    | 0.008 | 0.012 |
| C              | 0.10        | 0.15 | 0.25 | 0.004    | 0.006 | 0.010 |
| D              | 1.55        | 1.60 | 1.65 | 0.059    | 0.063 | 0.067 |
| E              | 0.70        | 0.80 | 0.90 | 0.027    | 0.031 | 0.035 |
| e              | 1.00 BSC    |      |      | 0.04 BSC |       |       |
| L              | 0.10        | 0.15 | 0.20 | 0.004    | 0.006 | 0.008 |
| H <sub>E</sub> | 1.50        | 1.60 | 1.70 | 0.061    | 0.063 | 0.065 |

- STYLE 1:
- PIN 1. BASE
  - EMITTER
  - COLLECTOR

## SOLDERING FOOTPRINT\*

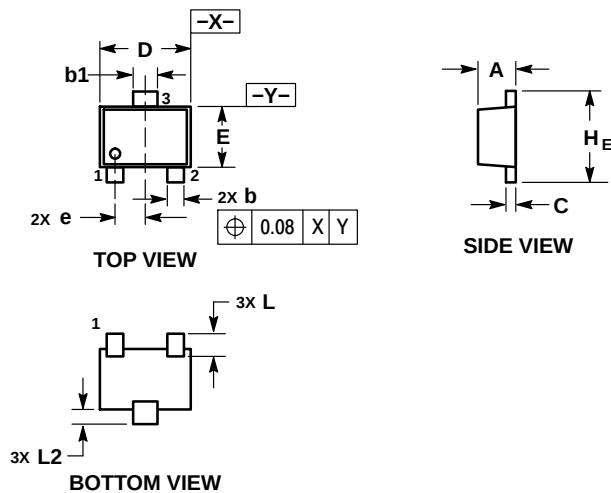


SCALE 10:1 (mm/inches)

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# PACKAGE DIMENSIONS

## SOT-723 CASE 631AA ISSUE D



### NOTES:

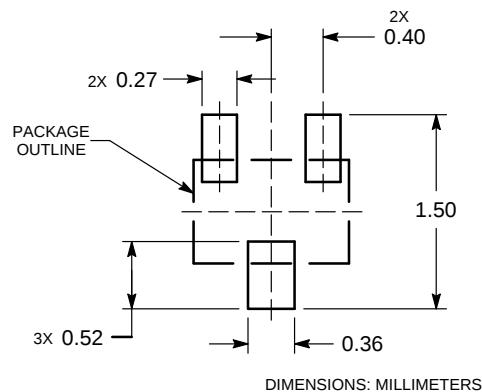
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

| DIM            | MILLIMETERS |      |      |
|----------------|-------------|------|------|
|                | MIN         | NOM  | MAX  |
| A              | 0.45        | 0.50 | 0.55 |
| b              | 0.15        | 0.21 | 0.27 |
| b1             | 0.25        | 0.31 | 0.37 |
| C              | 0.07        | 0.12 | 0.17 |
| D              | 1.15        | 1.20 | 1.25 |
| E              | 0.75        | 0.80 | 0.85 |
| e              | 0.40 BSC    |      |      |
| H <sub>E</sub> | 1.15        | 1.20 | 1.25 |
| L              | 0.29 REF    |      |      |
| L2             | 0.15        | 0.20 | 0.25 |

### STYLE 1:

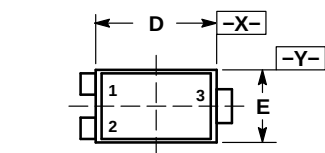
- PIN 1. BASE
- EMITTER
- COLLECTOR

## RECOMMENDED SOLDERING FOOTPRINT\*

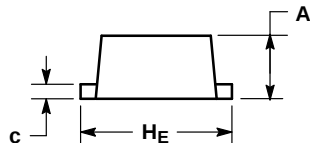


\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

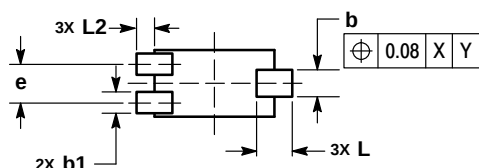
## PACKAGE DIMENSIONS

SOT-1123  
CASE 524AA  
ISSUE C

TOP VIEW



SIDE VIEW



BOTTOM VIEW

## NOTES:

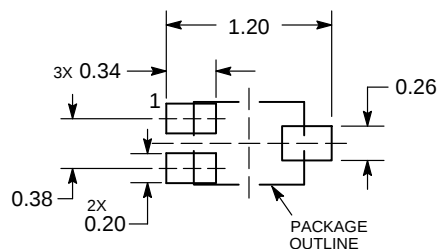
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

| DIM            | MILLIMETERS |      |
|----------------|-------------|------|
|                | MIN         | MAX  |
| A              | 0.34        | 0.40 |
| b              | 0.15        | 0.28 |
| b1             | 0.10        | 0.20 |
| c              | 0.07        | 0.17 |
| D              | 0.75        | 0.85 |
| E              | 0.55        | 0.65 |
| e              | 0.35        | 0.40 |
| H <sub>E</sub> | 0.95        | 1.05 |
| L              | 0.185       | REF  |
| L2             | 0.05        | 0.15 |

## STYLE 1:

1. BASE
2. EMITTER
3. COLLECTOR

## SOLDERING FOOTPRINT\*



DIMENSIONS: MILLIMETERS

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